




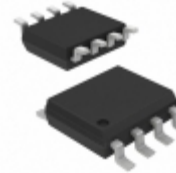



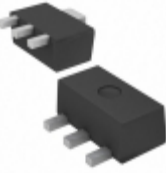
	ZXMN3A01FTC	
	Hersteller-Teilenummer:	ZXMN3A01FTC
	Hersteller / Marke:	Diodes Incorporated
	Teil der Beschreibung:	MOSFET N-CH 30V 1.8A SOT23-3
	Datenblätter:	 ZXMN3A01FTC.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 34951 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	ZXMN3A01FTC
Hersteller	Diodes Incorporated
Beschreibung	MOSFET N-CH 30V 1.8A SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	34951 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3
Verlustleistung (max)	625mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1.8A (Ta)
Rds On (Max) @ Id, Vgs	120 mOhm @ 2.5A, 10V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	3.9nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	190pF @ 25V
Verpackung	Tape & Reel (TR)




































ZXMN3A01FTC ist neu im Original, Suche ZXMN3A01FTC Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie ZXMN3A01FTC Diodes Incorporated mit Garantie und Vertrauen. Anfrage ZXMN3A01FTC: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>ZXMN3A01F ZETEX ZXMN3A01F ZETEX</p>	 <p>ZXMN3A02N8TA Diodes Incorporated MOSFET N-CH 30V 5.3A 8-SOIC</p>	 <p>ZXMN3A02X8TA Diodes Incorporated MOSFET N-CH 30V 5.3A 8-MSOP</p>	 <p>ZXMN3A02N8TC Diodes Incorporated MOSFET N-CH 30V 8SOIC</p>
 <p>ZXMN3A01E6TA Diodes Incorporated MOSFET N-CH 30V 2.4A SOT-23-6</p>	 <p>ZXMN3A01FTA Diodes Incorporated MOSFET N-CH 30V 1.8A SOT23-3</p>	 <p>ZXMN3A01E6TC Diodes Incorporated MOSFET N-CH 30V 2.4A SOT23-6</p>	 <p>ZXMN3A01ZTA Diodes Incorporated MOSFET N-CH 30V 3.3A SOT89</p>

heiße Teile

Mehr

 ZXMN2A02X8TA	 ZXMN2A02X8TC	 ZXMN2A03E6	 ZXMN2A03E6TA	 ZXMN2A04DN8
 ZXMN2A04DN8TA	 ZXMN2A04DN8TC	 ZXMN2A14FTA	 ZXMN2A14FTC	 ZXMN2AM832TA
 ZXMN2AMCTA	 ZXMN2B01FTA	 ZXMN2B01FTC	 ZXMN2B03E6TA	 ZXMN2B14FH
 ZXMN2B14FHHTA	 ZXMN2F30FH	 ZXMN2F30FHQTA	 ZXMN2F30FHHTA	 ZXMN2F34FH
 ZXMN2F34FHHTA	 ZXMN2F34MATA	 ZXMN3A01E6TA	 ZXMN3A01F	 ZXMN3A01FTA
 ZXMN3A01ZTA	 ZXMN3A02N8	 ZXMN3A02N8TA	 ZXMN3A02X8TA	 ZXMN3A03E6
 ZXMN3A03E6TA	 ZXMN3A04DN8	 ZXMN3A04DN8TA	 ZXMN3A04DN8TC	 ZXMN3A04K
 ZXMN3A04KTC	 ZXMN3A06D	 ZXMN3A06DN8	 ZXMN3A06DN8TA	 ZXMN3A06DN8TC
 ZXMN3A14F	 ZXMN3A14FQTA	 ZXMN3A14FTA	 ZXMN3A14FTC	 ZXMN3AM832TA
 ZXMN3B01FTA	 ZXMN3B01FTC	 ZXMN3B04N8	 ZXMN3B04N8TA	 ZXMN3B04N8TC

Contact us: Info@Y-IC.com

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